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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP331, TLP332

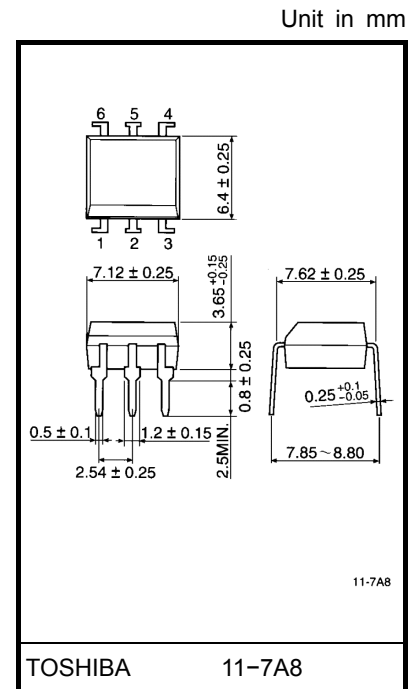
- Office Machine
- Household Use Equipment
- Programmable Controllers
- AC / DC-Input Module
- Telecommunication

The TOSHIBA TLP331 and TLP332 consists of a gallium arsenide infrared emitting diode optically coupled to a photo-transistor in a six lead plastic DIP package.

This photocoupler provides the unique feature of high current transfer ratio at both low output voltage and low input current. This makes it ideal for use in low power logic circuits, telecommunications equipment and portable electronics isolation applications.

TLP332 is no-base internal connection for high-EMI environments.

- Collector-emitter voltage: 55V (min.)
- Isolation voltage: 5000Vrms (min.)
- UL recognized: UL1577, file no. E67349
- Current transfer ratio



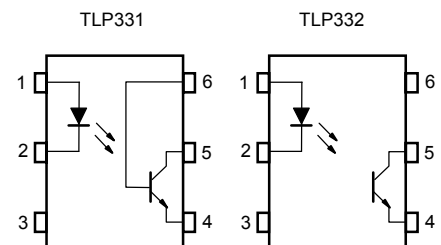
Weight: 0.4 g

| Classi- fication (*) | Current Transfer Ratio (min.) | | | Marking Of Classi- fication |
|----------------------------|-------------------------------|--------------------------|------------------------|--------------------------------------|
| | Ta = 25°C | | | |
| | If = 1mA VCE = 0.5V | If = 0.5mA VCE = 1.5V | If = 1mA VCE = 0.5V | |
| Rank BV | 200% | 100% | 100% | BV |
| Standard | 100% | 50% | 50% | BV, blank |

(*) Ex. Standard: TLP331
Rank BV: TLP331(BV)

(Note) Application type name for certification test,
please use standard product type name, i.e.
TLP331(BV): TLP331

Pin Configurations (top view)



- 1: ANODE
- 2: CATHODE
- 3: NC
- 4: EMITTER
- 5: COLLECTOR
- 6: BASE

- 1: ANODE
- 2: CATHODE
- 3: NC
- 4: EMITTER
- 5: COLLECTOR
- 6: NC

Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | Symbol | Rating | Unit |
|--|--|-------------------------------|---------|------------------|
| LED | Forward current | I_F | 50 | mA |
| | Forward current derating (Ta ≥ 39°C) | $\Delta I_F / ^\circ\text{C}$ | -0.7 | mA / °C |
| | Peak forward current (100µs pulse, 100pps) | I_{FP} | 1 | A |
| | Reverse Voltage | V_R | 5 | V |
| | Junction temperature | T_j | 125 | °C |
| Detector | Collector-emitter voltage | V_{CEO} | 55 | V |
| | Collector-base voltage (TLP331) | V_{CBO} | 80 | V |
| | Emitter-collector voltage | V_{ECO} | 7 | V |
| | Emitter-base voltage (TLP331) | V_{EBO} | 7 | V |
| | Collector current | I_C | 50 | mA |
| | Power dissipation | P_C | 150 | mW |
| | Power dissipation derating (Ta ≥ 25°C) | $\Delta P_C / ^\circ\text{C}$ | -1.5 | mW / °C |
| | Junction temperature | T_j | 125 | °C |
| Storage temperature range | | T_{stg} | -55~125 | °C |
| Operating temperature range | | T_{opr} | -55~100 | °C |
| Lead soldering temperature (10s) | | T_{sol} | 260 | °C |
| Total package power dissipation | | P_T | 250 | mW |
| Total package power dissipation derating (Ta ≥ 25°C) | | $P_T / ^\circ\text{C}$ | -2.5 | mW / °C |
| Isolation voltage (AC, 1min., RH ≤ 60%) (Note 1) | | BV_S | 5000 | V _{rms} |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|-----------------------|-----------|------|------|------|------|
| Supply voltage | V_{CC} | — | 5 | 25 | V |
| Forward current | I_F | — | 1.6 | 25 | mA |
| Collector current | I_C | — | 1 | 10 | mA |
| Operating temperature | T_{opr} | -25 | — | 75 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

| Characteristic | | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|----------------|---|---------------|---|------|------|------|---------------|
| LED | Forward voltage | V_F | $I_F = 10\text{mA}$ | 1.0 | 1.15 | 1.3 | V |
| | Reverse current | I_R | $V_R = 5\text{V}$ | — | — | 10 | μA |
| | Capacitance | C_T | $V = 0, f = 1\text{MHz}$ | — | 30 | — | pF |
| Detector | Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C = 0.5\text{mA}$ | 55 | — | — | V |
| | Emitter-collector breakdown voltage | $V_{(BR)ECO}$ | $I_E = 0.1\text{mA}$ | 7 | — | — | V |
| | Collector-base breakdown voltage (TLP331) | $V_{(BR)CBO}$ | $I_C = 0.1\text{mA}$ | 80 | — | — | V |
| | Emitter-base breakdown voltage (TLP331) | $V_{(BR)EBO}$ | $I_E = 0.1\text{mA}$ | 7 | — | — | V |
| | Collector dark current | I_{CEO} | $V_{CE} = 24\text{V}$ | — | 10 | 100 | nA |
| | | | $V_{CE} = 24\text{V}, T_a = 85^\circ\text{C}$ | — | 2 | 50 | μA |
| | Collector dark current (TLP331) | I_{CER} | $V_{CE} = 24\text{V}, T_a = 85^\circ\text{C}$ $R_{BE} = 1\text{M}\Omega$ | — | 0.5 | 10 | μA |
| | Collector dark current (TLP331) | I_{CBO} | $V_{CB} = 10\text{V}$ | — | 0.1 | — | nA |
| | DC forward current gain (TLP331) | h_{FE} | $V_{CE} = 5\text{V}, I_C = 0.5\text{mA}$ | — | 1000 | — | — |
| | Capacitance (collector to emitter) | C_{CE} | $V = 0, f = 1\text{MHz}$ | — | 12 | — | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|--------------------------------------|---------------------------|---|------|------|------|---------------|
| Current transfer ratio | I_C / I_F | $I_F = 1\text{mA}, V_{CE} = 0.5\text{V}$ Rank BV | 100 | — | 1200 | % |
| | | | 200 | — | 1200 | |
| Low input CTR | $I_C / I_{F(\text{low})}$ | $I_F = 0.5\text{mA}, V_{CE} = 1.5\text{V}$ Rank BV | 50 | — | — | % |
| | | | 100 | — | — | |
| Base photo-current (TLP331) | I_{PB} | $I_F = 1\text{mA}, V_{CB} = 5\text{V}$ | — | 10 | — | μA |
| Collector-emitter saturation voltage | $V_{CE(\text{sat})}$ | $I_C = 0.5\text{mA}, I_F = 1\text{mA}$ $I_C = 1\text{mA}, I_F = 1\text{mA}$ Rank BV | — | — | 0.4 | V |
| | | | — | 0.2 | — | |
| | | | — | — | 0.4 | |

Coupled Electrical Characteristics (Ta = 25~75°C)

| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|------------------------|---------------------------|---|------|------|------|------|
| Current transfer ratio | I_C / I_F | $I_F = 1\text{mA}, V_{CE} = 0.5\text{V}$ Rank BV | 50 | — | — | % |
| | | | 100 | — | — | |
| Low input CTR | $I_C / I_{F(\text{low})}$ | $I_F = 0.5\text{mA}, V_{CE} = 1.5\text{V}$ Rank BV | — | 50 | — | % |
| | | | — | 100 | — | |

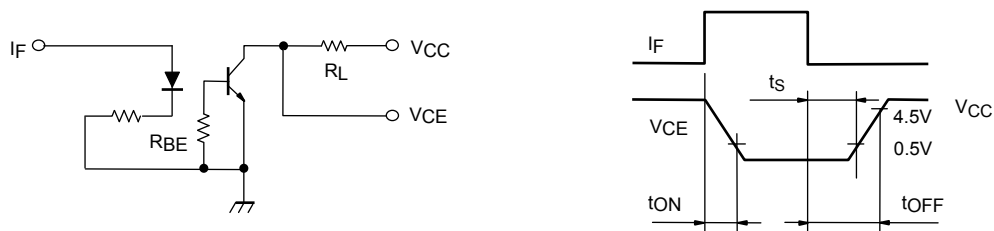
Isolation Characteristics (Ta = 25°C)

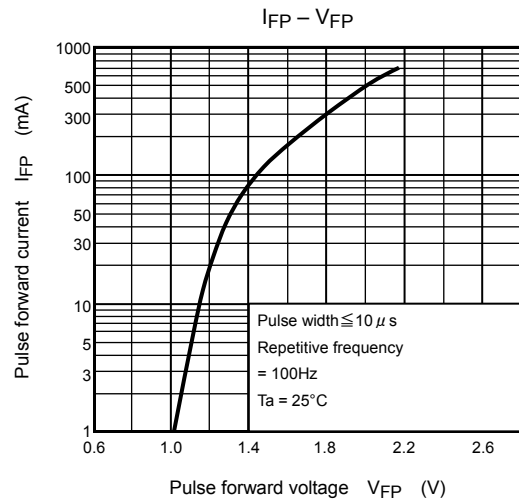
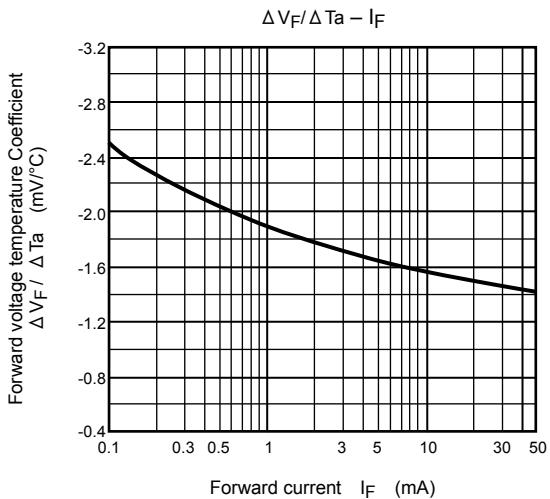
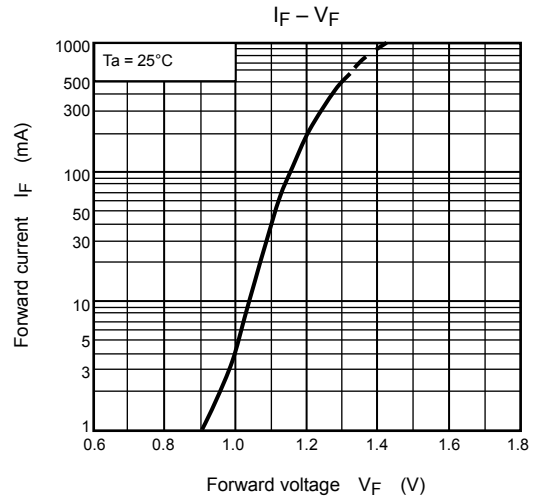
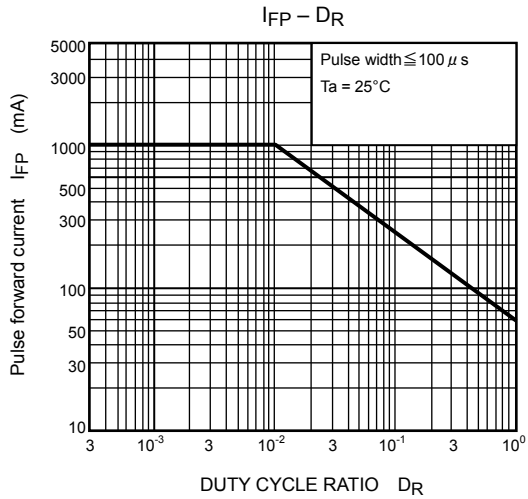
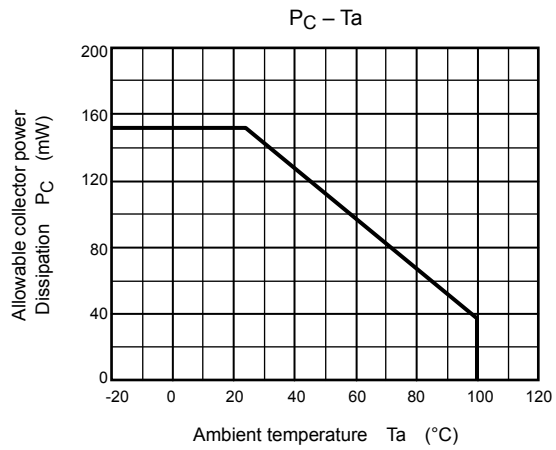
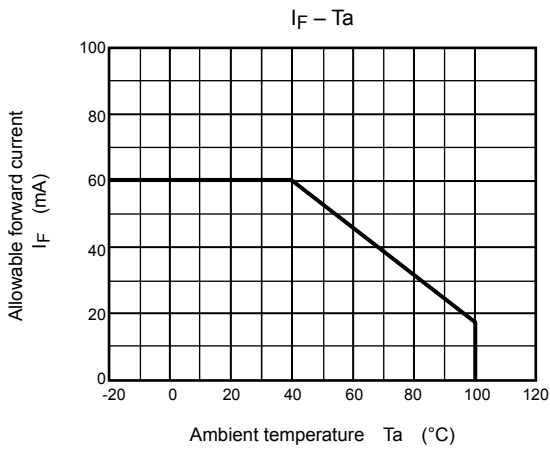
| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-------------------------------|-----------------|------------------------------|--------------------|------------------|------|------------------|
| Capacitance (input to output) | C _S | V _S = 0, f = 1MHz | — | 0.8 | — | pF |
| Isolation resistance | R _S | V = 500V | 5×10 ¹⁰ | 10 ¹⁴ | — | Ω |
| Isolation voltage | BV _S | AC, 1 minute | 5000 | — | — | V _{rms} |
| | | AC, 1 second, in oil | — | 10000 | — | |
| | | DC, 1 minute, in oil | — | 10000 | — | V _{dc} |

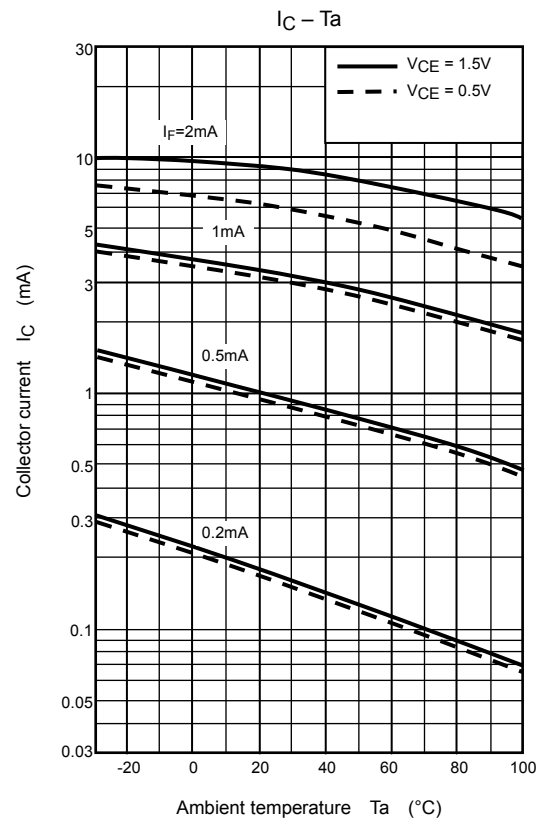
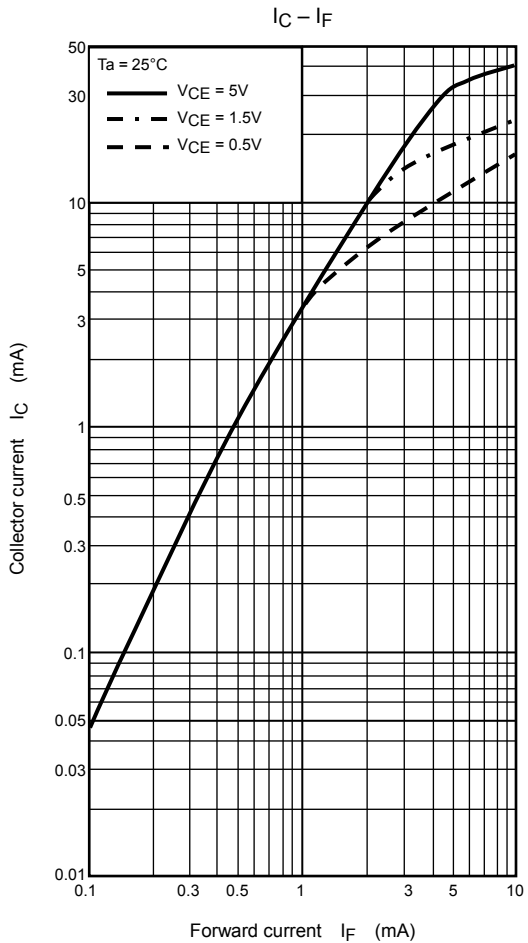
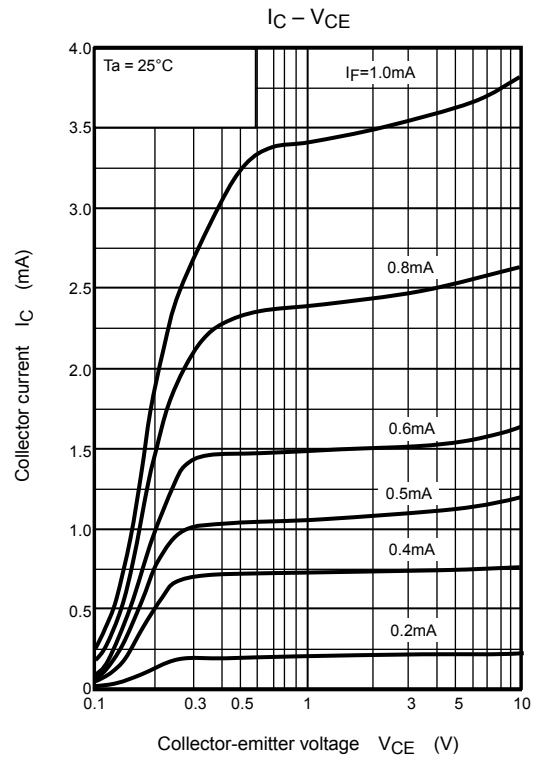
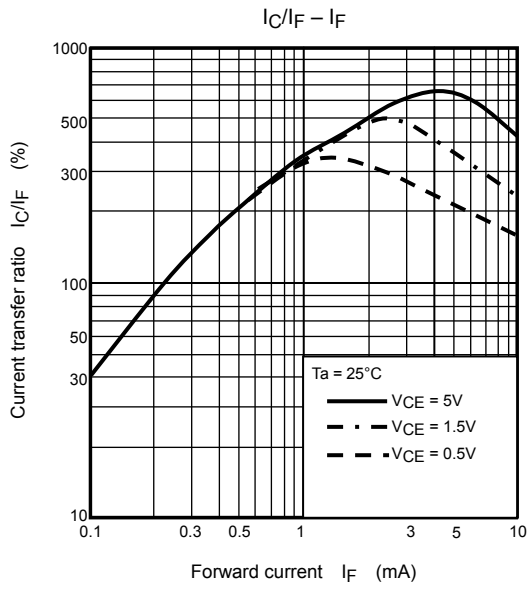
Switching Characteristics (Ta = 25°C)

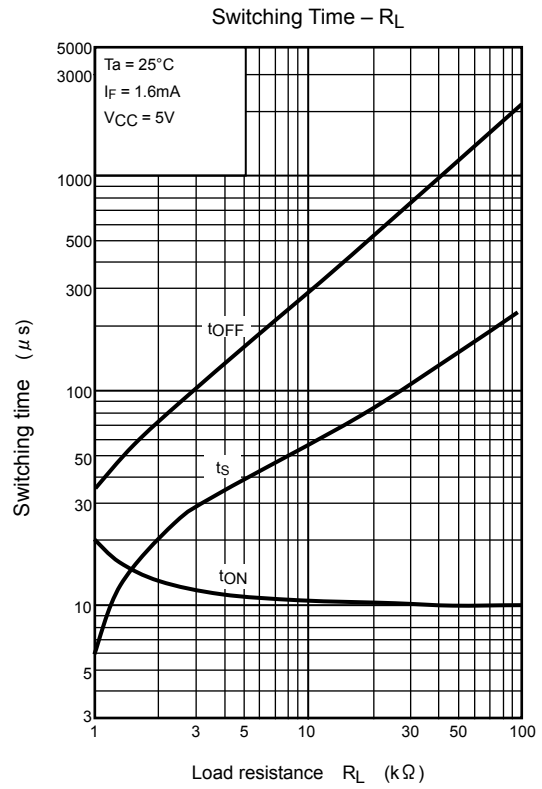
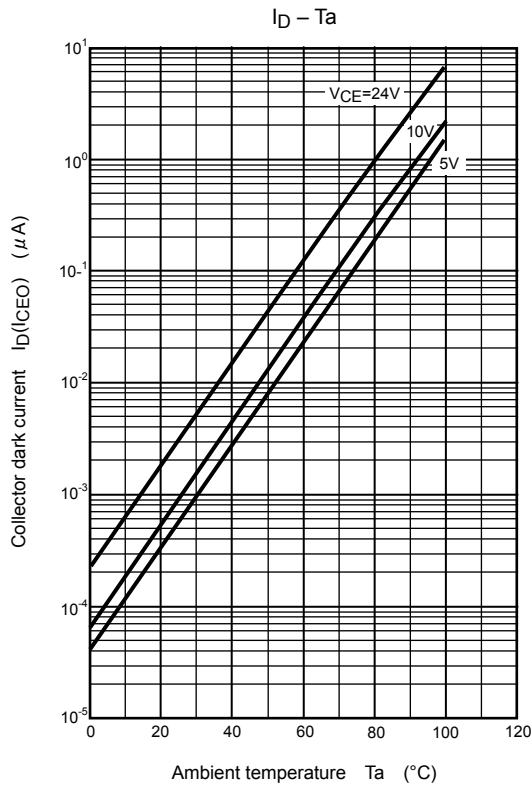
| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|----------------|------------------|--|------|------|------|------|
| Rise time | t _r | V _{CC} = 10V I _C = 2mA R _L = 100Ω | — | 8 | — | μs |
| Fall time | t _f | | — | 8 | — | |
| Turn-on time | t _{on} | | — | 10 | — | |
| Turn-off time | t _{off} | | — | 8 | — | |
| Turn-on time | t _{ON} | R _L = 4.7kΩ (Fig.1) R _{BE} = OPEN V _{CC} = 5V, I _F = 1.6mA | — | 10 | — | μs |
| Storage time | t _S | | — | 50 | — | |
| Turn-off time | t _{OFF} | | — | 300 | — | |
| Turn-on time | t _{ON} | R _L = 4.7kΩ (Fig.1) R _{BE} = 470kΩ (TLP331) V _{CC} = 5V, I _F = 1.6mA | — | 12 | — | μs |
| Storage time | t _S | | — | 30 | — | |
| Turn-off time | t _{OFF} | | — | 100 | — | |

Fig. 1 Switching time test circuit









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20070701-EN

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